

Provisional Data

Insulated Gate Bi-Polar Transistor Type T1200EB45E

Absolute Maximum Ratings

	VOLTAGE RATINGS	MAXIMUM LIMITS	UNITS
V_{CES}	Collector – emitter voltage	4500	V
$V_{DC\ link}$	Permanent DC voltage for 100 FIT failure rate	2800	V
V_{GES}	Peak gate – emitter voltage	± 20	V

	RATINGS	MAXIMUM LIMITS	UNITS
$I_{C(DC)}$	Continuous DC collector current, IGBT	1200	A
I_{CRM}	Repetitive peak collector current, $t_p=1ms$, IGBT	2400	A
I_{ECO}	Maximum reverse emitter current, $t_p=100\mu s$, (note 2 & 3)	1200	A
P_{MAX}	Maximum power dissipation, IGBT (note 2)	12.5	kW
$T_{j\ op}$	Operating temperature range	-40 to +125	$^{\circ}C$
T_{stg}	Storage temperature range	-40 to +125	$^{\circ}C$

Notes: -

- 1) Unless otherwise indicated $T_j = 125^{\circ}C$
- 2) $T_{sink} = 25^{\circ}C$, double side cooled
- 3) The use of an anti-parallel diode is recommended

Characteristics

IGBT Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS	
V _{CE(sat)}	Collector – emitter saturation voltage	-	2.8	3.2	I _C = 1200A, V _{GE} = 15V, T _j = 25°C	V	
		-	3.6	4.1	I _C = 1200A, V _{GE} = 15V	V	
V _{T0}	Threshold voltage	-	-	1.69	Current range: 500 – 1500A	V	
r _T	Slope resistance	-	-	1.97		mΩ	
V _{GE(TH)}	Gate threshold voltage	-	5.3	-	V _{CE} = V _{GE} , I _C = 125mA	V	
I _{CES}	Collector – emitter cut-off current	-	20	50	V _{CE} = V _{CES} , V _{GE} = 0V	mA	
I _{GES}	Gate leakage current	-	-	±15	V _{GE} = ±20V	μA	
C _{ies}	Input capacitance	-	200	-	V _{CE} = 25V, V _{GE} = 0V, f = 1MHz	nF	
t _{d(on)}	Turn-on delay time	-	1.8	-	I _C = 1200A, V _{CE} = 2800V V _{GE} = ±15V, L _S = 250nH R _{g(ON)} = 3.3Ω, R _{g(OFF)} = 3.3Ω, C _{GE} = 133nF. Freewheel diode type E1500VF450. (Note 3)	μs	
t _{r(V)}	Rise time	-	3.0	-		μs	
Q _{g(on)}	Turn-on gate charge	-	12	-		μC	
E _{on}	Turn-on energy	-	5.7	-		J	
t _{d(off)}	Turn-off delay time	-	1.6	-		μs	
t _f	Fall time	-	2.2	-		μs	
Q _{g(off)}	Turn-off gate charge	-	10	-		μC	
E _{off}	Turn-off energy	-	5.1	-		J	
I _{SC}	Short circuit current	-	4750	-		V _{GE} = +15V, V _{CC} = 2800V, V _{CEmax} ≤ V _{CES} , t _p ≤ 10μs	A

Thermal Characteristics

	PARAMETER	MIN	TYP	MAX	TEST CONDITIONS	UNITS
R _{thJK}	Thermal resistance junction to sink, IGBT	-	-	8.0	Double side cooled	K/kW
		-	-	12.5	Collector side cooled	K/kW
		-	-	23.3	Emitter side cooled	K/kW
F	Mounting force	25	-	35	Note 2	kN
W _t	Weight	-	1.2	-		kg

Notes:-

- 1) Unless otherwise indicated T_j = 125°C.
- 2) Consult application note 2008AN01 for detailed mounting requirements.
- 3) C_{GE} is additional gate - emitter capacitance added to output of gate drive circuit.

Curves

Figure 1 – Typical collector-emitter saturation voltage characteristics

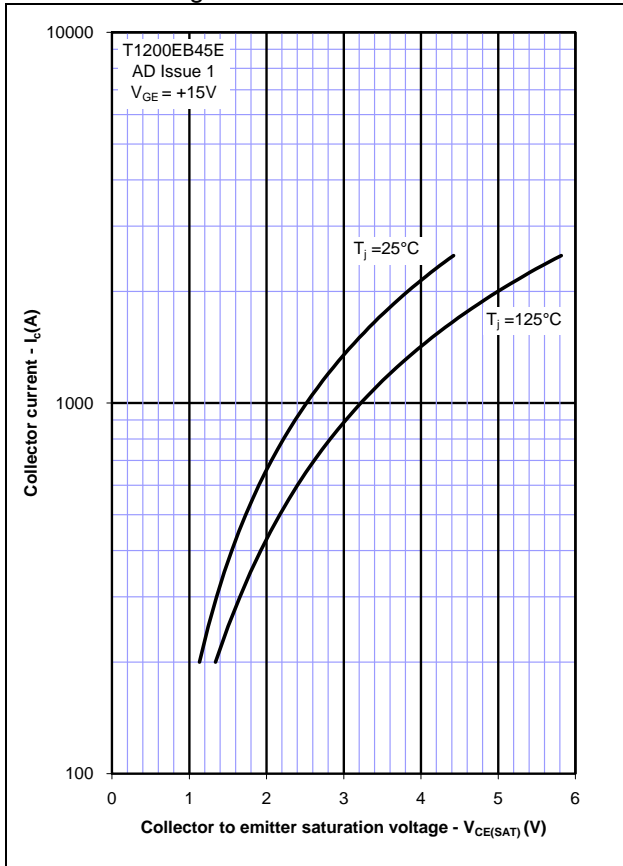


Figure 2 – Typical output characteristic

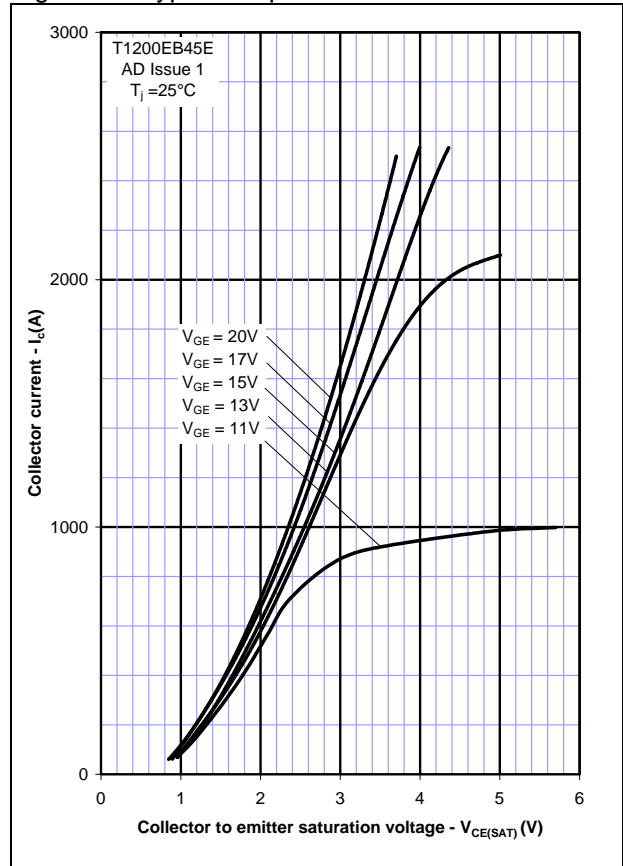


Figure 3 – Typical output characteristic

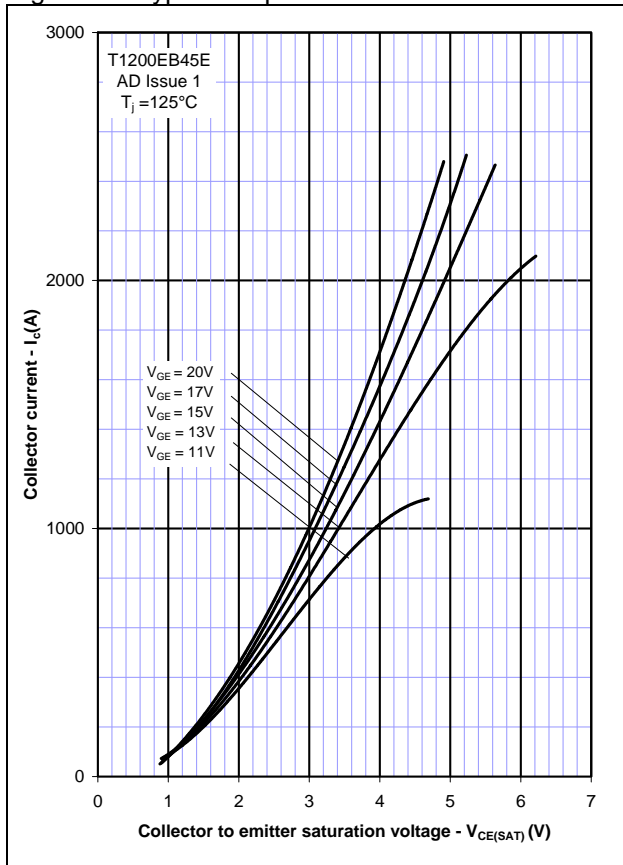


Figure 4 – Typical turn-on delay time vs gate resistance

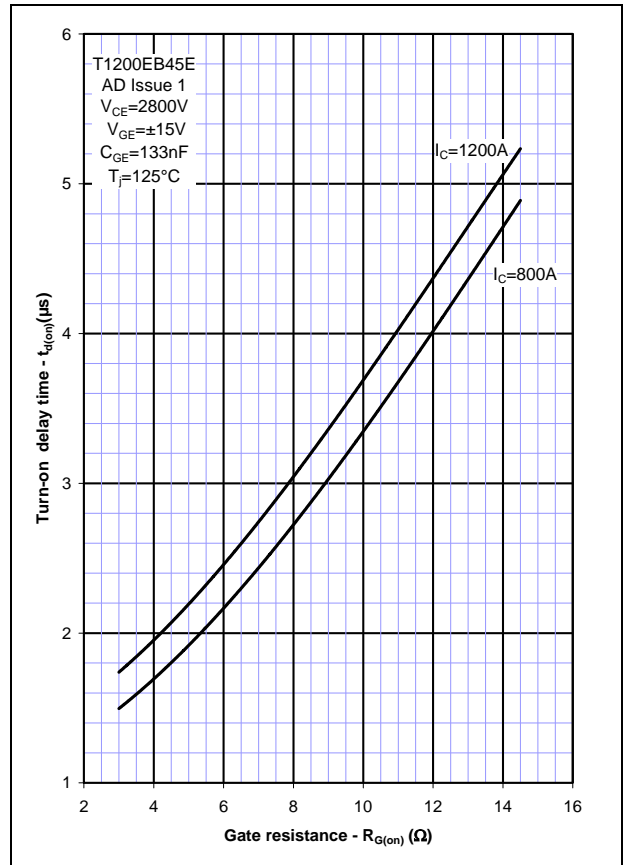


Figure 5 – Typical turn-off delay time vs. gate resistance

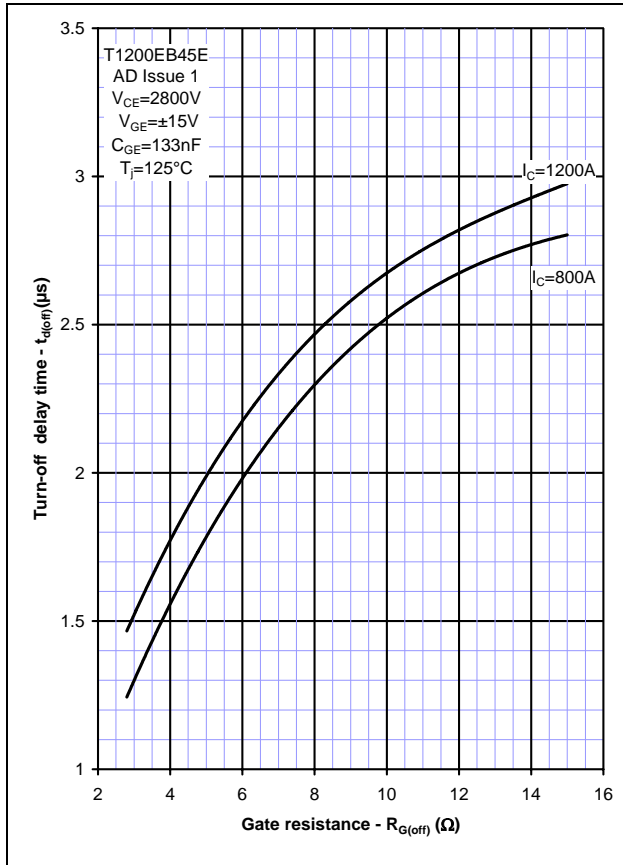


Figure 6 – Typical turn-on energy vs. collector current

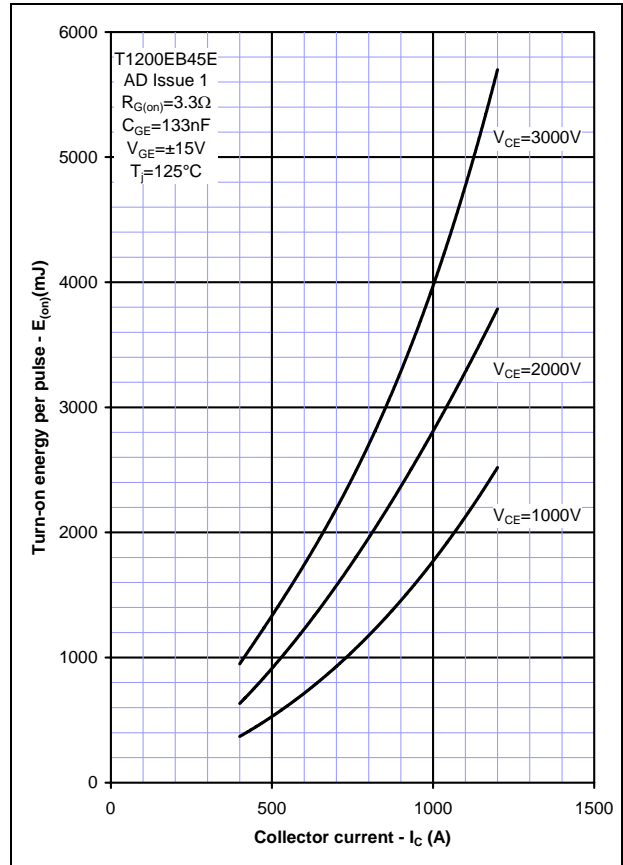


Figure 7 – Typical turn-on energy vs. di/dt

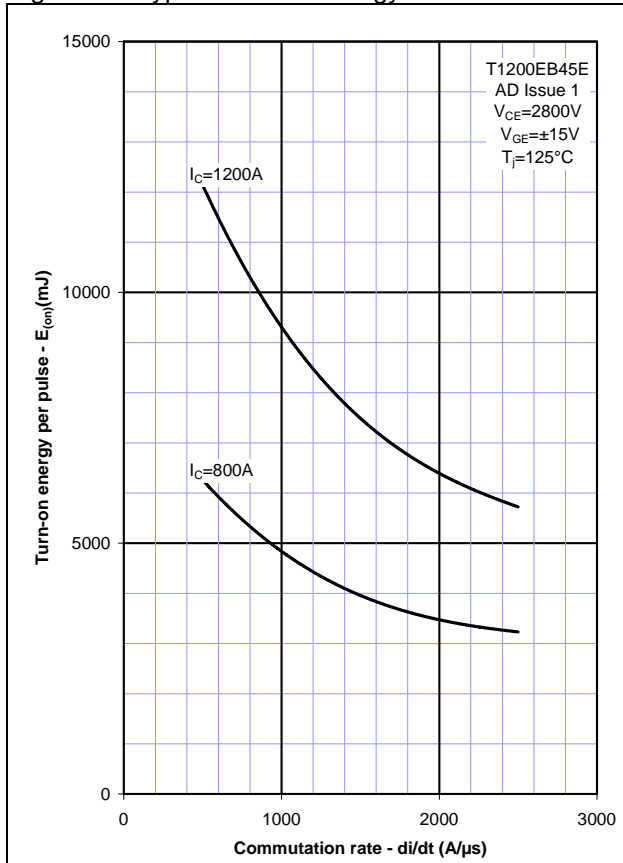


Figure 8 – Typical turn-off energy vs. collector current

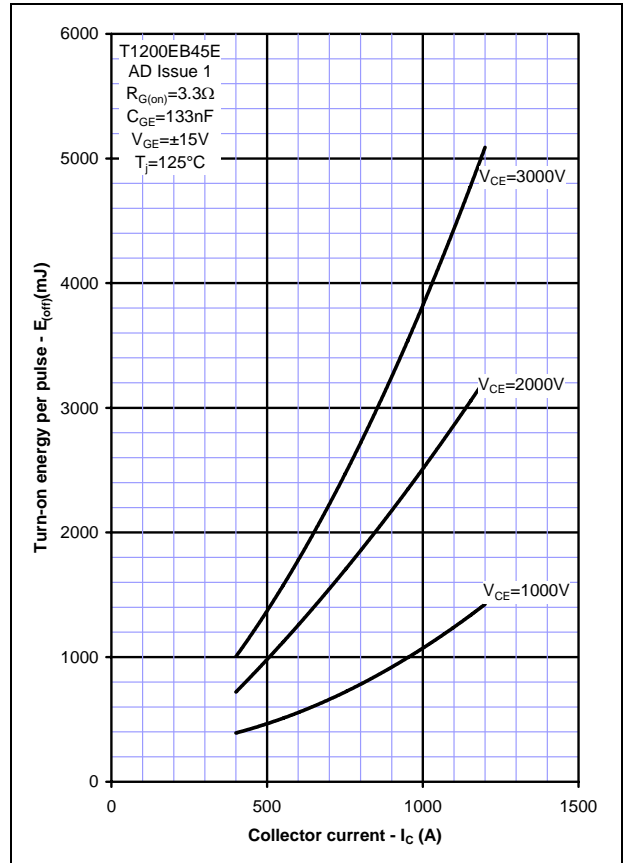


Figure 9 – Turn-off energy vs voltage

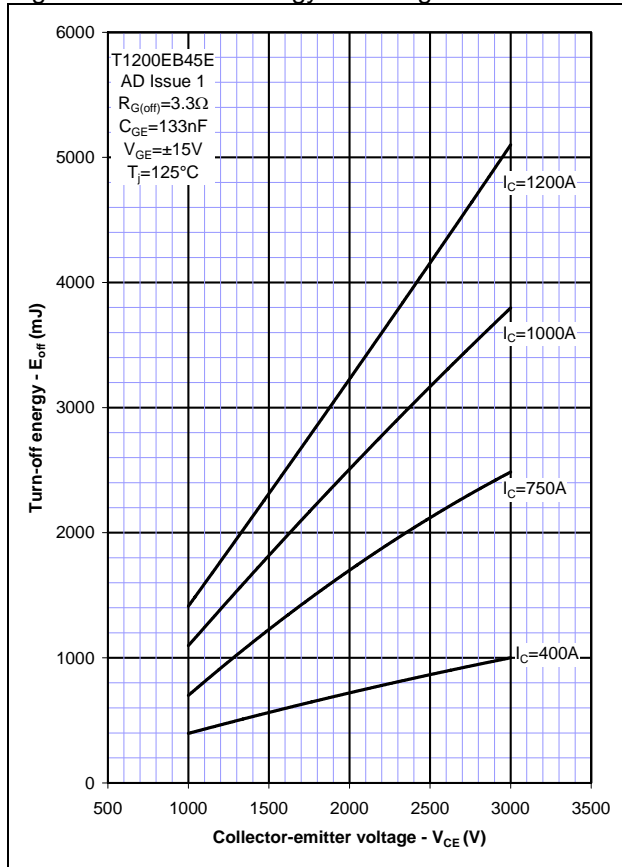


Figure 10 – Safe operating area

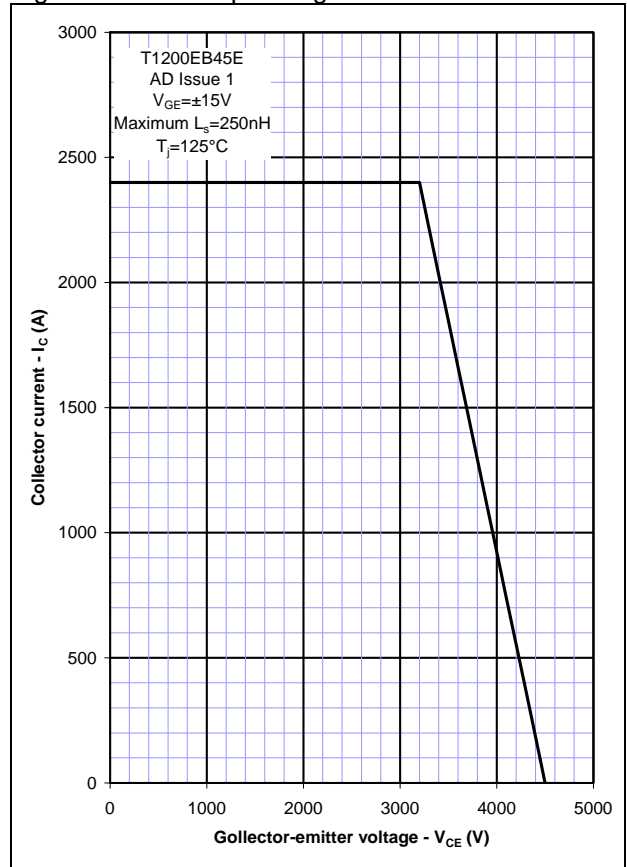
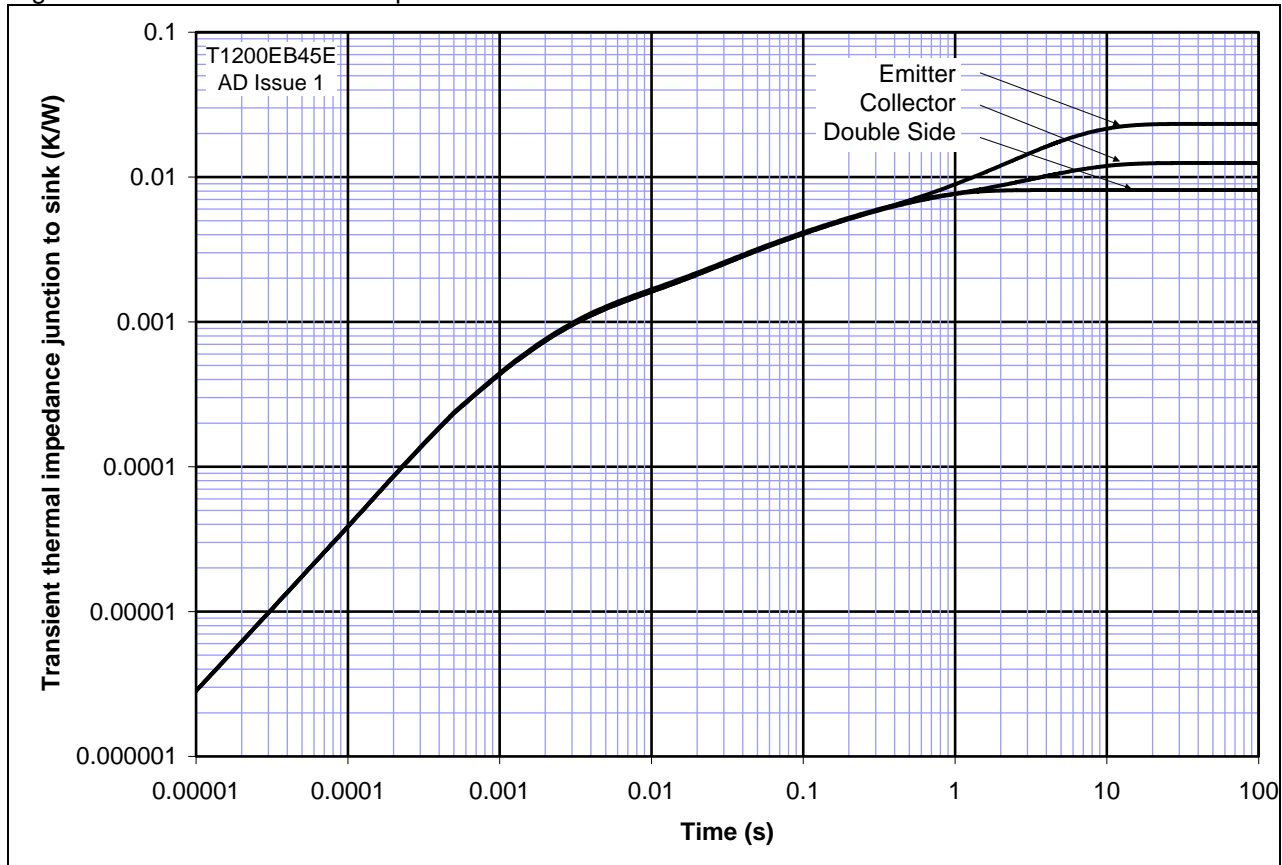
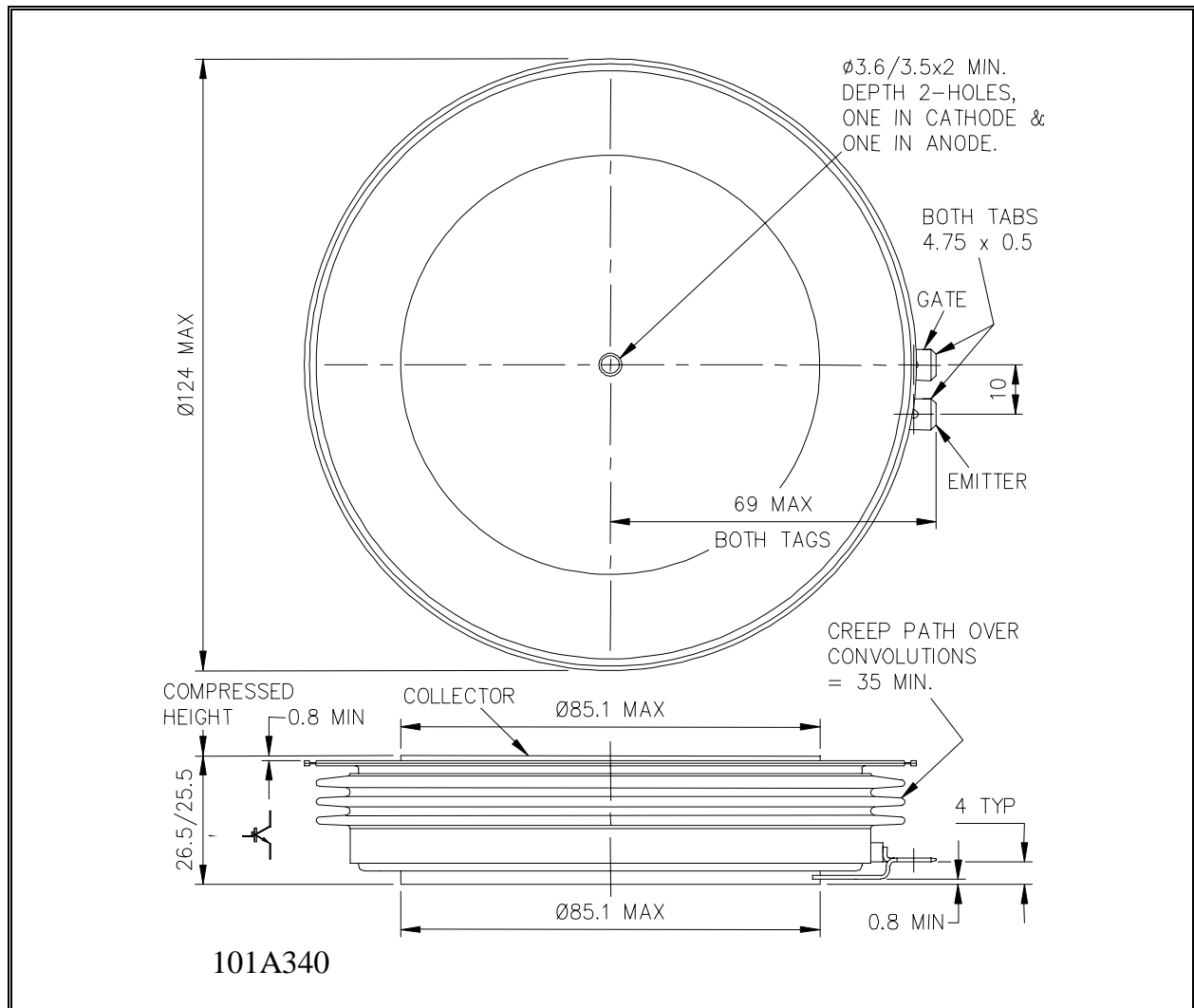


Figure 11 – Transient thermal impedance



Outline Drawing & Ordering Information



ORDERING INFORMATION (Please quote 10 digit code as below)

T1200	EB	45	E
Fixed type Code	Fixed Outline Code	Voltage Grade $V_{CES}/100$ 45	Fixed format code

Typical order code: T1200EB45E ($V_{CES} = 4500V$)

IXYS Semiconductor GmbH
Edisonstraße 15
D-68623 Lampertheim
Tel: +49 6206 503-0
Fax: +49 6206 503-627
E-mail: marcom@ixys.de
IXYS Corporation
1590 Buckeye Drive
Milpitas CA 95035-7418
Tel: +1 (408) 457 9000
Fax: +1 (408) 496 0670
E-mail: sales@ixys.net

WESTCODE
An IXYS Company

www.westcode.com

www.ixys.com

Westcode Semiconductors Ltd
Langley Park Way, Langley Park,
Chippenham, Wiltshire, SN15 1GE.
Tel: +44 (0)1249 444524
Fax: +44 (0)1249 659448
E-mail: WSL.sales@westcode.com
IXYS Long Beach
IXYS Long Beach, Inc
2500 Mira Mar Ave, Long Beach
CA 90815
Tel: +1 (562) 296 6584
Fax: +1 (562) 296 6585
E-mail: service@ixyslongbeach.com

The information contained herein is confidential and is protected by Copyright. The information may not be used or disclosed except with the written permission of and in the manner permitted by the proprietors Westcode Semiconductors Ltd.

© Westcode Semiconductors Ltd.

In the interest of product improvement, Westcode reserves the right to change specifications at any time without prior notice.

Devices with a suffix code (2-letter, 3-letter or letter/digit/letter combination) added to their generic code are not necessarily subject to the conditions and limits contained in this report.



Disclaimer Notice - Information furnished is believed to be accurate and reliable. However, users should independently evaluate the suitability of and test each product selected for their own applications. Littelfuse products are not designed for, and may not be used in, all applications. Read complete Disclaimer Notice at www.littelfuse.com/disclaimer-electronics.